









	<h2 style="color: red;">NTP5860NG</h2>
	<p>Hersteller-Teilenummer: NTP5860NG</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 60V 220A TO-220-3</p> <hr/> <p>Datenblätter:  NTP5860NG.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 34438 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTP5860NG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 220A TO-220-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	34438 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	283W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	220A (Tc)
Rds On (Max) @ Id, Vgs	3 mOhm @ 75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	180nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	10760pF @ 25V
Verpackung	Tube



















































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Sie können auch interessiert sein:

 <p>NTP5860NL O NTP5860NL O</p>	 <p>NTP5863NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 97A TO-220AB</p>	 <p>NTP5412NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO-220AB</p>	 <p>NTP5860NLG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 220A TO-220-3</p>
 <p>NTP5860N VB NTP5860N VB</p>	 <p>NTP5411NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 80A TO-220AB</p>	 <p>NTP5862NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V TO-220-3</p>	 <p>NTP5426NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 120A TO-220AB</p>

heiße Teile

Mehr

 NTP22N06L	 NTP27N06G	 NTP27N06L	 NTP2955G	 NTP30N06L
 NTP30N06LG	 NTP30N20	 NTP30N20G	 NTP35N15	 NTP35N15G
 NTP4302G	 NTP45N06	 NTP45N06G	 NTP45N06L	 NTP45N06LG
 NTP477M04TDR	 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG
 NTP5411NG	 NTP5412NG	 NTP5426N	 NTP5426NG	 NTP5860N
 NTP5860NL	 NTP5860NLG	 NTP5862NG	 NTP5863N	 NTP5863NG
 NTP5864N	 NTP5864NG	 NTP60N06	 NTP60N06G	 NTP60N06L
 NTP60N06LG	 NTP6410AN	 NTP6410ANG	 NTP6411AN	 NTP6411ANG
 NTP6412AN	 NTP6412ANG	 NTP6413AN	 NTP6413ANG	 NTP6448ANG
 NTP65N02R	 NTP65N02RG	 NTP75N03-006	 NTP75N03-06	 NTP75N03-06G

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